AlGaAs Infrared Laser Diode

6-2D-LD85-028_Rev.02

ADL-85051SM

850nm 5mW LD

By converting the external APC circuit board into an ASIC, we package the APC circuit into a traditional TO-can together with the laser chip. From now on, single package APC function included laser diode is realized.

Powered with Arima's proprietary APC **LASER DIODE**[™] technology, **ADL-85051SM** is your perfect solution for the stable light power output, compact size, high brightness laser light source.

Features

- 1. 850nm 5mW 50°C high reliable operation
- 2. Saving space and cost of laser module
- 3. Voltage driven LD, easy to use
- 4. Highly stable laser output power
- 5. Strong reverse bias protection
- 6. High ESD sustainability voltage
- 7. High speed short protection
- 8. Power source reverse protection

Applications

- 1. Industry : laser level, illumination, meter, scanner, detector
- 2. Consumer : point light, sweeper, game lighting
- 3. Health : special wavelength light source

Absolute maximum ratings

Parameter	Symbol	Rating	Unit
Power supply voltage	V _{cc}	2.7~6.0	V
Laser optical output power	Po	5.0	mW
Case temperature	Tc	-10 ~ +50	°C
Storage temperature	T _{stg}	-40 ~ +85	°C

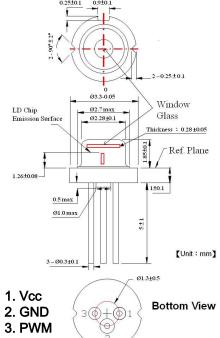
Electrical and optical characteristics (T_c=25 °C)

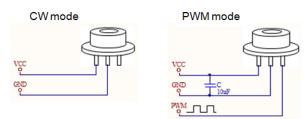
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Wavelength	λ	840	850	860	nm	Po=5mW , Vcc=3V	
Operating current	I _{cc}	-	25	35	mA	Po=5mW , Vcc=3V	
Parallel divergence angle	θ _{//}	6	10	14	Deg		
Perpendicular divergence angle	θ_{\perp}	27	31	36	Deg	Po=5mW,Vcc=3V	
Parallel FFP deviation angle	Δθ _{//}	-3.0	0	+3.0	Deg		
Perpendicular FFP deviation angle	$\Delta \theta_{\perp}$	-3.0	0	+3.0	Deg		
Emission point accuracy	∆x∆y∆z	-80	0	+80	um		
Power-Temp stability (50~25°C)	ΔP _{oT}	-15	-	10	%	Po=5mW , Vcc=3V	
Power-Temp stability (-10~25°C)	ΔP _{oT}	-15	-	10	%	Po=5mW , Vcc=3V	
Power-Vcc stability (6.0~3.0V)	ΔP _{oV}	-10	-	10	%	Po=5mW , Temp=25°C	
Power-Vcc stability (2.7~3.0V)	ΔP _{oV}	-15	-	10	%	Po=5mW , Temp=25°C	
Power Range	ΔPo	-10	-	10	%	Po=5mW , Vcc=3V	
PWM Control mode	PWM	100	-	2000	KHz	Add 10uF capacitance [,] Duty cycle=50%	

* Effective heat sink is recommended on 6V case due to extra heat ARIMA LASERS CORP.

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E-MAIL: Ldsales@arimalasers.com | www.arimalasers.com <u>For reference only.</u> Contents above are subject to change without notice.







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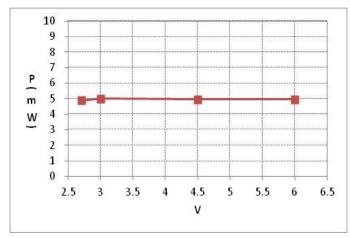
850nm 5mW I D

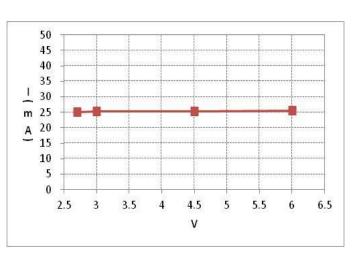
Block Diagram:

- Traditional LD needs to connect an external APC circuit board for 1. the constant power operation.
- 2. ADL-85051SM has an APC IC in the TO-3.3mm package, and APC circuit board can keep the same optical power.
- 3. Add capacitance is recommended for stabilizing the PWM control.
- Battery reverse protection is recommended for protecting the 4. APC Circuit.
- 5. If the setting power is below 50% of the target power, it is recommended to add >1uF capacitor between Vcc and Gnd.

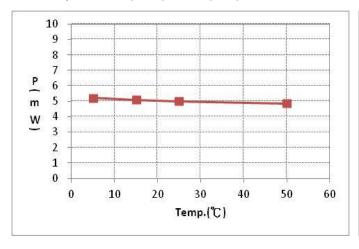
Product Characteristic Curve:

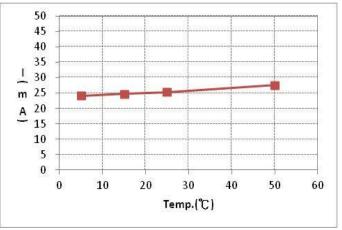
1. Vcc vs. Po(mW) & Icc(mA)



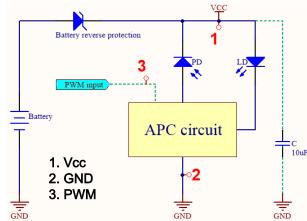


2. Temp. vs. Po(mW) & Icc(mA)









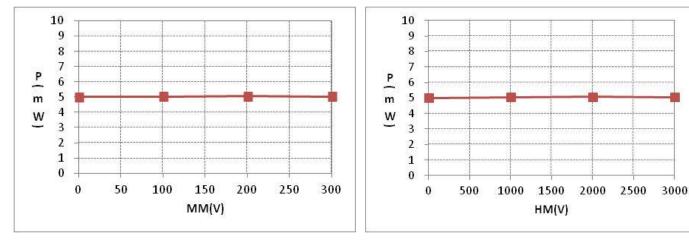
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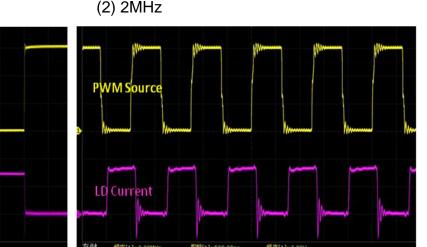
ADL-85051SM

850nm 5mW LD

3. ESD-V(HM&MM) vs. Po(mW)



PWM-Freq(100kHz ,2000kHz) vs. lcc waveform
100KHz



Special Note:

LD Current

PWM Source

- 1. The laser diode cannot be replaced directly when the power supply is started normally.
- 2. It is recommended to use soft-start circuit before driving the laser diode.
- Electrical specifications do not apply when operating the device outside of its rated operating conditions. Absolute maximum ratings indicate limits beyond which damage may occur, please avoid occur voltage surge when using.
- 4. The laser products start-up times within 100us.

Precautions

- * To protect laser from overdriving condition, setting VR to maximum value before you turn on Vcc can minimized the laser output power.
- * Do not operate the device above the maximum rating condition, even momentarily. It may cause unexpected permanent damage to the device.
- * Semiconductor laser device is very sensitive to electrostatic discharge. High voltage spike current may change the characteristics of the device, or malfunction at any time during its service period. Therefore, proper measures for preventing electrostatic discharge are strongly recommended.
- * To obtain a stable characteristic and good reliability, the effective heat sink is necessary. So it is recommended that always apply proper heat sink before the device is operating.
- * Do not look into the laser beam directly by bare eyes. The laser beam may cause severe damage to human eyes.

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